

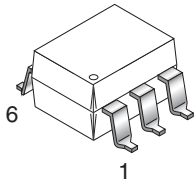
H11AV1-M

H11AV1A-M

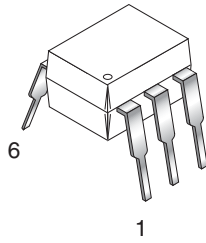
H11AV2-M

H11AV2A-M

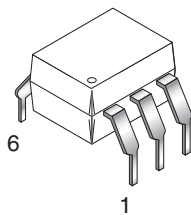
PACKAGE OUTLINE



H11AV1S-M, H11AV2S-M

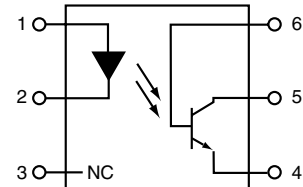


H11AV1-M, H11AV2-M



H11AV1A-M, H11AV2A-M

SCHEMATIC



PIN 1. ANODE
2. CATHODE
3. NO CONNECTION
4. EMITTER
5. COLLECTOR
6. BASE

DESCRIPTION

The general purpose optocouplers consist of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a 6-pin dual in-line white package.

FEATURES

- H11AV1 and H11AV2 feature 0.3" input-output lead spacing
- H11AV1A and H11AV2A feature 0.4" input-output lead spacing
- UL recognized (File #E90700, Vol. 2)
- VDE recognized (File #102497)
- Add option V (e.g., H11AV1AV-M)

APPLICATIONS

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs

H11AV1-M

H11AV1A-M

H11AV2-M

H11AV2A-M

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)			
Parameter	Symbol	Value	Units
TOTAL DEVICE			
Storage Temperature	T _{STG}	-40 to +150	°C
Operating Temperature	T _{OPR}	-40 to +100	°C
Wave solder temperature (see page 9 for reflow solder profiles)	T _{SOL}	260 for 10 sec	°C
Total Device Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	250	mW
		2.94	mW/°C
EMITTER			
DC/Average Forward Input Current	I _F	60	mA
Reverse Input Voltage	V _R	6	V
LED Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	120	mW
		1.41	mW/°C
DETECTOR			
Collector-Emitter Voltage	V _{CEO}	70	V
Collector-Base Voltage	V _{CBO}	70	V
Emitter-Collector Voltage	V _{ECO}	7	V
Detector Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	150	mW
		1.76	mW/°C

H11AV1-M

H11AV1A-M

H11AV2-M

H11AV2A-M

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

INDIVIDUAL COMPONENT CHARACTERISTICS

Parameter	Test Conditions	Symbol	Min	Typ*	Max	Unit
EMITTER						
Input Forward Voltage ($I_F = 10\text{ mA}$)	$T_A = 25^\circ\text{C}$	V_F	0.8	1.18	1.5	V
	$T_A = -55^\circ\text{C}$		0.9	1.28	1.7	
	$T_A = 100^\circ\text{C}$		0.7	1.05	1.4	
Reverse Leakage Current	($V_R = 6.0\text{ V}$)	I_R			10	μA
DETECTOR						
Collector-Emitter Breakdown Voltage	($I_C = 1.0\text{ mA}$, $I_F = 0$)	BV_{CEO}	70	100		V
Collector-Base Breakdown Voltage	($I_C = 100\text{ }\mu\text{A}$, $I_F = 0$)	BV_{CBO}	70	120		V
Emitter-Collector Breakdown Voltage	($I_E = 100\text{ }\mu\text{A}$, $I_F = 0$)	BV_{ECO}	7	10		V
Collector-Emitter Dark Current	($V_{CE} = 10\text{ V}$, $I_F = 0$)	I_{CEO}		1	50	nA
Collector-Base Dark Current	($V_{CB} = 10\text{ V}$)	I_{CBO}		0.5		nA
Capacitance	($V_{CE} = 0\text{ V}$, $f = 1\text{ MHz}$)	C_{CE}		8		pF

ISOLATION CHARACTERISTICS

Characteristic	Test Conditions	Symbol	Min	Typ*	Max	Units
Input-Output Isolation Voltage	($f = 60\text{ Hz}$, $t = 1\text{ sec}$)	V_{ISO}	7500			Vac(pk)
Isolation Resistance	($V_{I-O} = 500\text{ VDC}$)	R_{ISO}	10^{11}			Ω
Isolation Capacitance	($V_{I-O} = 0\text{ V}$, $f = 1\text{ MHz}$)	C_{ISO}		0.2	2	pF

Note

* Typical values at $T_A = 25^\circ\text{C}$

H11AV1-M

H11AV1A-M

H11AV2-M

H11AV2A-M

TRANSFER CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)							
DC Characteristic	Test Conditions	Symbol	Device	Min	Typ*	Max	Unit
Current Transfer Ratio, Collector to Emitter	$(I_F = 10\text{ mA}, V_{CE} = 10\text{ V})$	CTR	H11AV1 H11AV1A	100		300	%
			H11AV2 H11AV2A	50			
Collector-Emitter Saturation Voltage	$(I_C = 2\text{ mA}, I_F = 20\text{ mA})$	$V_{CE(SAT)}$	All			0.4	V
AC Characteristic	$(I_C = 2\text{ mA}, V_{CC} = 10\text{ V}, R_L = 100\Omega)$ (Fig. 11)	T_{ON}	All			15	μs
Non-Saturated Turn-on Time							
Non Saturated Turn-off Time	$(I_C = 2\text{ mA}, V_{CC} = 10\text{ V}, R_L = 100\Omega)$ (Fig. 11)	T_{ON}	All			15	μs

* Typical values at $T_A = 25^\circ\text{C}$

H11AV1-M

H11AV1A-M

H11AV2-M

H11AV2A-M

TYPICAL PERFORMANCE CURVES

Fig. 1 LED Forward Voltage vs. Forward Current

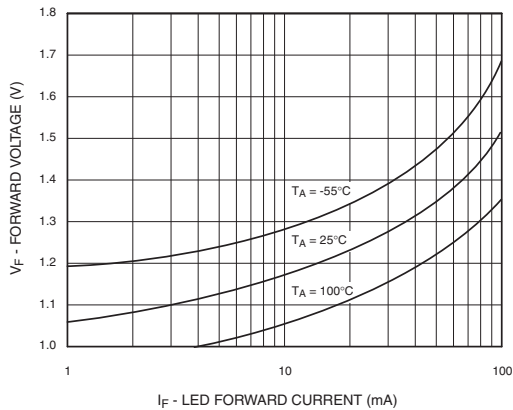


Fig. 2 Normalized CTR vs. Forward Current

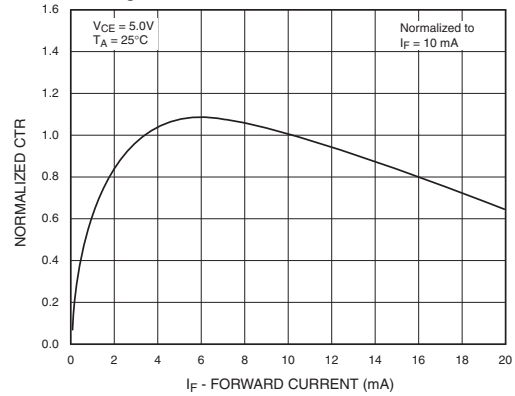


Fig. 3 Normalized CTR vs. Ambient Temperature

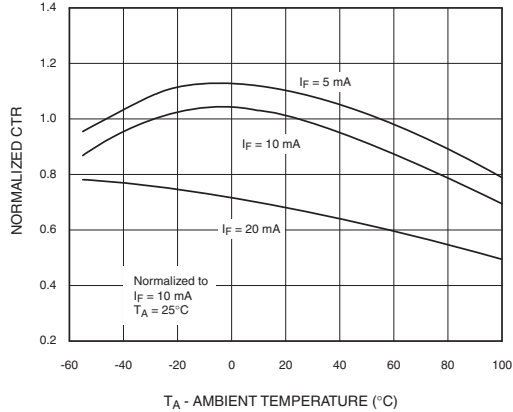


Fig. 4 CTR vs. RBE (Unsaturated)

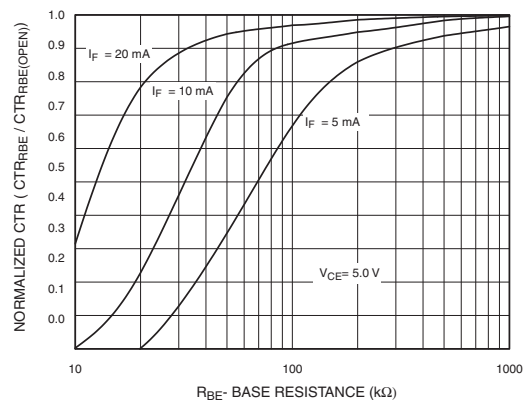


Fig. 5 CTR vs. RBE (Saturated)

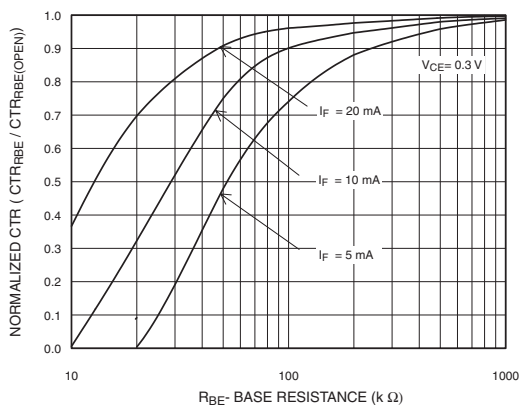
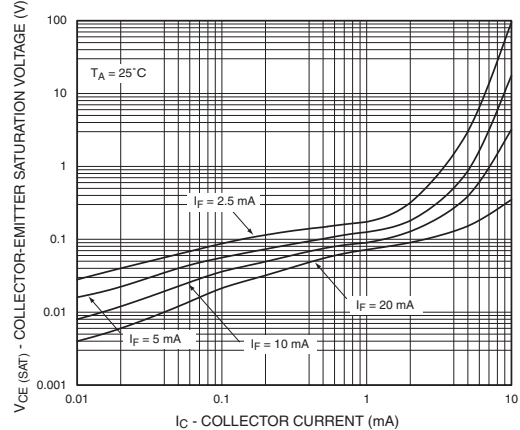


Fig. 6 Collector-Emitter Saturation Voltage vs. Collector Current



H11AV1-M

H11AV1A-M

H11AV2-M

H11AV2A-M

Fig. 7 Switching Speed vs. Load Resistor

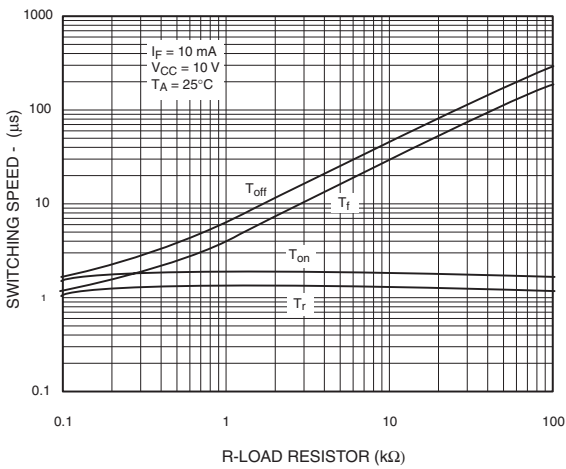


Fig. 8 Normalized t_{on} vs. R_{BE}

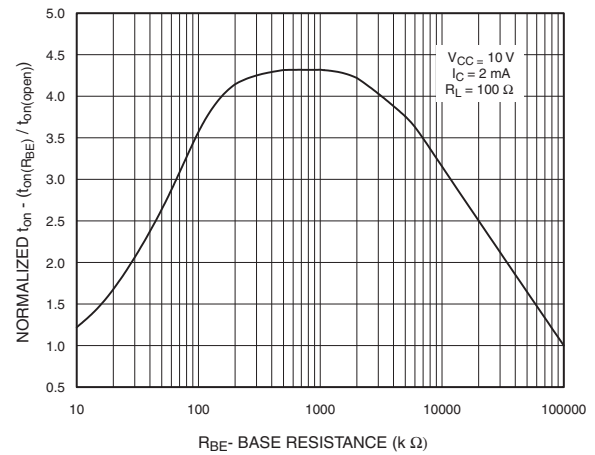


Fig. 9 Normalized t_{off} vs. R_{BE}

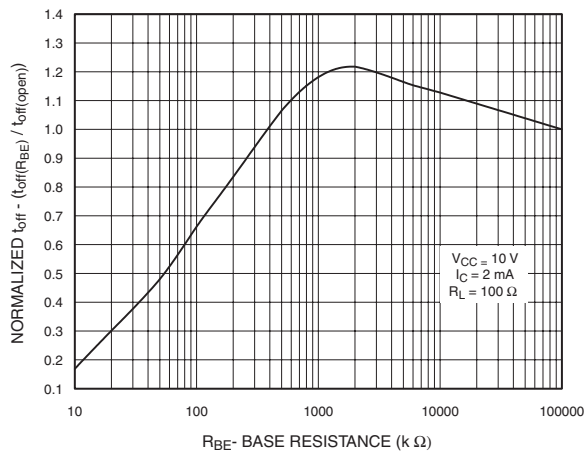


Fig. 10 Dark Current vs. Ambient Temperature

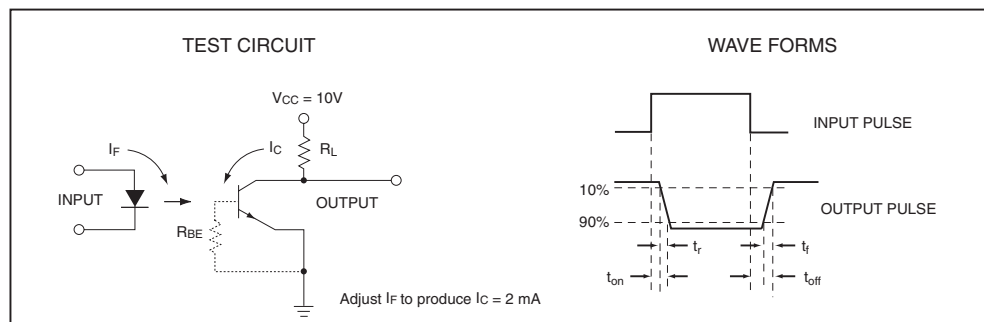
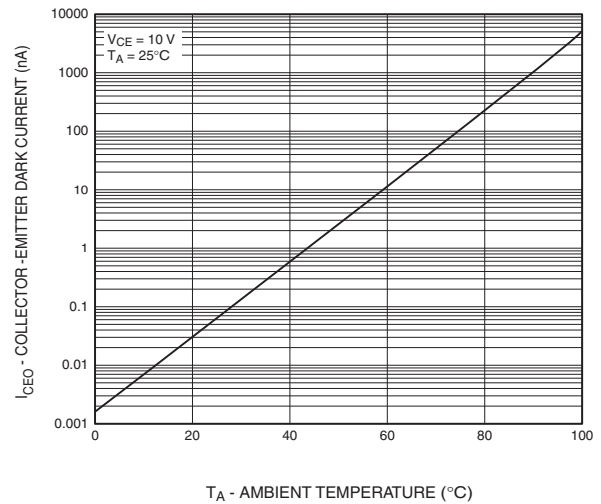


Figure 11. Switching Time Test Circuit and Waveforms

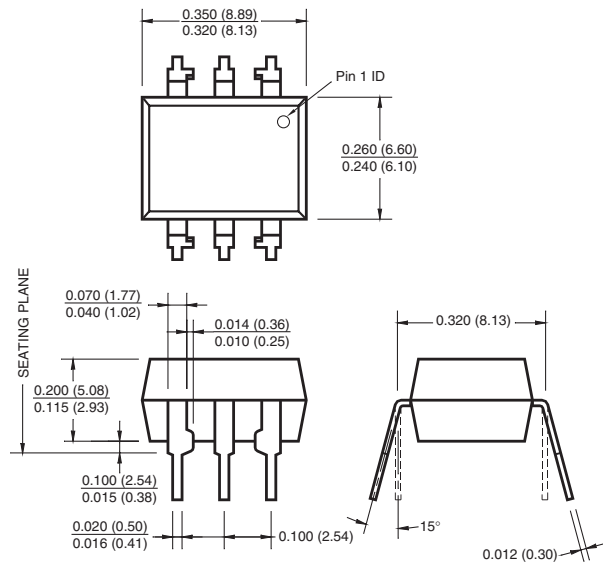
H11AV1-M

H11AV1A-M

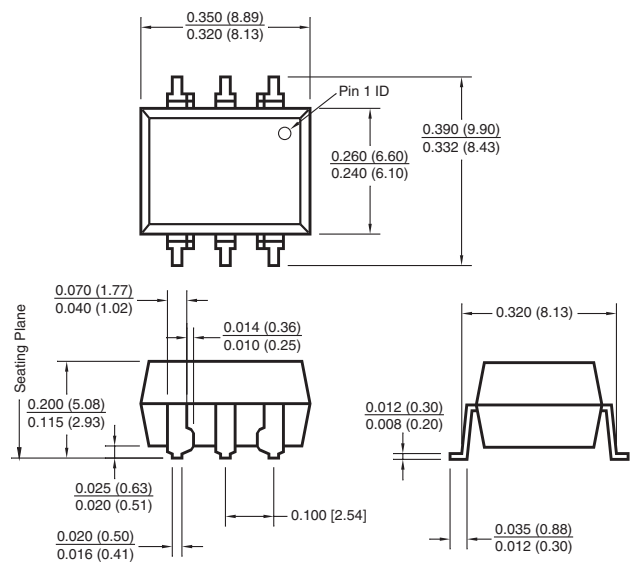
H11AV2-M

H11AV2A-M

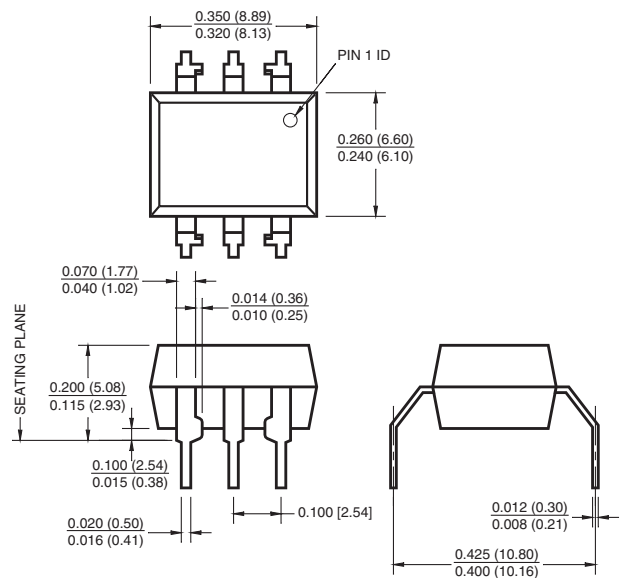
Package Dimensions (Through Hole)



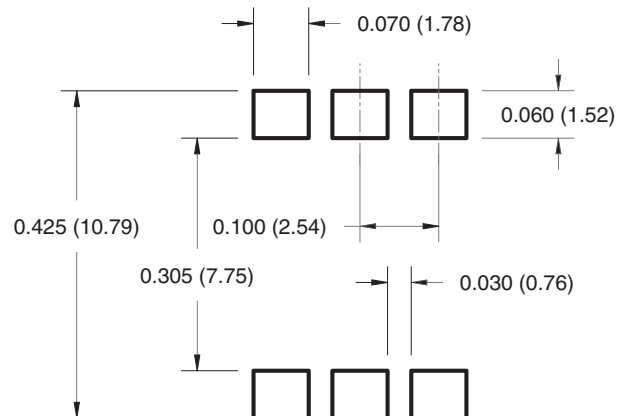
Package Dimensions (Surface Mount)



Package Dimensions (0.4" Lead Spacing)



Recommended Pad Layout for Surface Mount Leadform



NOTE

All dimensions are in inches (millimeters)

H11AV1-M

H11AV1A-M

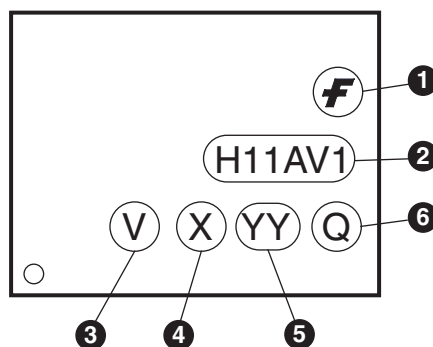
H11AV2-M

H11AV2A-M

ORDERING INFORMATION

Order Entry Identifier		
Order Entry Identifier	Option	Example
S	Surface Mount Lead Bend	H11AV1S-M
SR2	Surface Mount; Tape and reel	H11AV1SR2-M
N/A	0.4" Lead Spacing	H11AV1A-M
V	VDE 0884	H11AV1V-M
N/A	VDE 0884, 0.4" Lead Spacing	H11AV1AV-M
SV	VDE 0884, Surface Mount	H11AV1SV-M
SR2V	VDE 0884, Surface Mount, Tape & Reel	H11AV1SR2V-M

MARKING INFORMATION



White Package

Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code • One digit for white package parts, e.g., '3'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

*Note – Parts built in the white package (M suffix) that do not have the 'V' option (see definition 3 above) that are marked with date code '325' or earlier are marked in the portrait format.

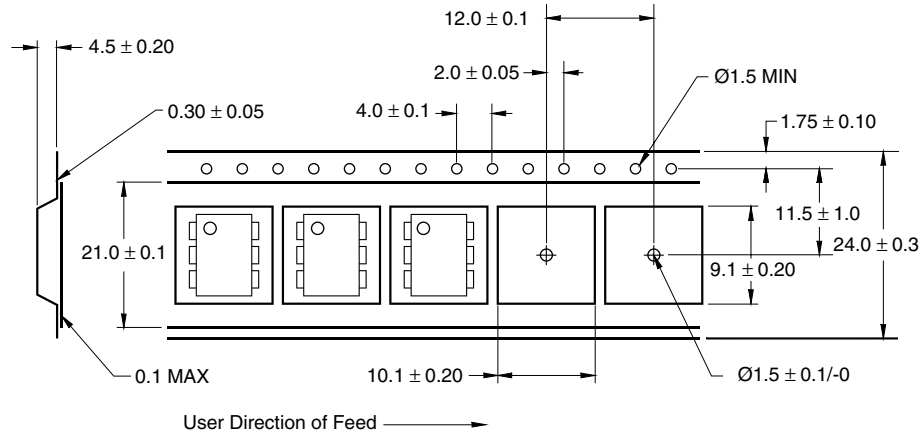
H11AV1-M

H11AV1A-M

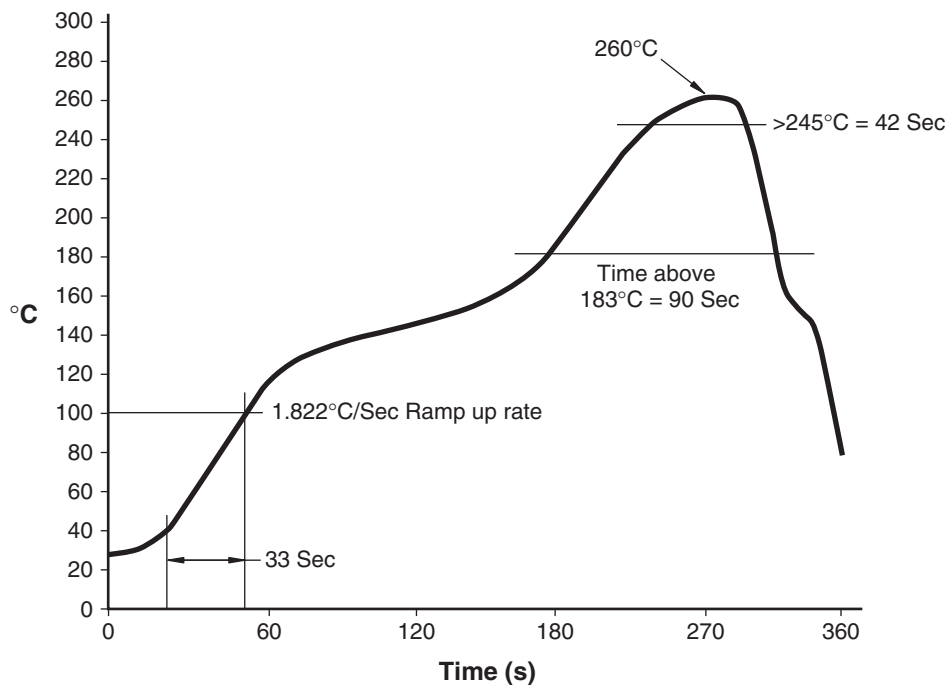
H11AV2-M

H11AV2A-M

Carrier Tape Specifications



Reflow Profile



H11AV1-M**H11AV1A-M****H11AV2-M****H11AV2A-M**

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